



N-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
	90mΩ @ V _{GS} = 4.5V	2.8A
20V	120mΩ @ V _{GS} = 2.5V	2.4A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)), yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- **Power Management Functions**
- **DC-DC Converters**
- Motor Control

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

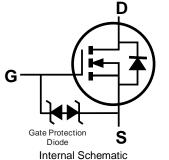
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)

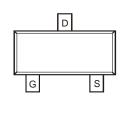






Top View





Top View

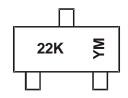
Ordering Information (Note 4)

Part Number	Case	Packaging
DMG2302UK-7	SOT23	3,000/Tape & Reel
DMG2302UK-13	SOT23	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



22K = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015) M = Month (ex: 9 = September)

Date Code Key

Year	2015		2016	2017		2018	2019		2020	2021		2022
Code	C		D	Е		F	G		Н			J
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Au	g Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Drain-Source Voltage		V_{DSS}	20	V	
Gate-Source Voltage		V_{GSS}	±12	V	
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$ Steady $T_A = +25^{\circ}C$ State $T_A = +70^{\circ}C$			I _D	2.8 2.2	А
Maximum Continuous Body Diode Forward Curre	ent (Note 6)	Is	1.1	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle =	1%)	I _{DM}	12	Α	

Thermal Characteristics

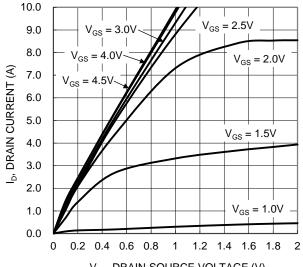
Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)		P_{D}	0.66	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	192	°C/W
Total Power Dissipation (Note 6)		P_{D}	1.1	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	115	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)				•	•	
Drain-Source Breakdown Voltage	BV _{DSS}	20	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	_		10	μΑ	V _{DS} = 16V, V _{GS} = 0V
Gate-Source Leakage	I_{GSS}	_	_	±10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)	_					
Gate Threshold Voltage	V _{GS(TH)}	0.3	0.6	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250\mu A$
Static Drain-Source On-Resistance			61	90	mΩ	$V_{GS} = 4.5V, I_D = 3.6A$
Static Drain-Source On-Resistance	R _{DS(ON)}		80	120	11177	V _{GS} = 2.5V, I _D = 3.1A
Diode Forward Voltage	V_{SD}	_	0.7	1.2	V	V _{GS} = 0V, I _S = 1.0A
DYNAMIC CHARACTERISTICS (Note 8)				•	•	
Input Capacitance	C _{ISS}	_	130	_	pF	10)/)/
Output Capacitance	Coss	_	26	_	pF	$V_{DS} = 10V, V_{GS} = 0V$ -f = 1.0MHz
Reverse Transfer Capacitance	C _{RSS}	_	18	_	pF	1 = 1.01/11 12
Gate Resistance	Rg	_	2.7	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Q_G	_	1.4	_	nC	
Total Gate Charge (V _{GS} = 10V)	Q_G	_	2.8	_	nC	101/1 0.04
Gate-Source Charge	Q _{GS}	_	0.1	_	nC	$V_{DS} = 10V, I_D = 3.6A$
Gate-Drain Charge	Q_{GD}	_	0.5	_	nC	1
Turn-On Delay Time	t _{D(ON)}	_	0.6	_	ns	
Turn-On Rise Time	t _R	_	2.7	_	ns	$V_{DS} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t _{D(OFF)}	_	4.2	_	ns	$R_G = 1\Omega$, $R_L = 2.78\Omega$
Turn-Off Fall Time	t _F	_	1.7	_	ns	1
Reverse Recovery Time	t _{RR}	_	5.3	_	ns	$I_F = 3.6A$, di/dt = 100A/ μ s
Reverse Recovery Charge	Q _{RR}	_	0.5	_	nC	$I_F = 3.6A$, di/dt = 100A/ μ s

- 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.
 6. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.





 $V_{\rm DS}$, DRAIN-SOURCE VOLTAGE (V) Figure 1. Typical Output Characteristic

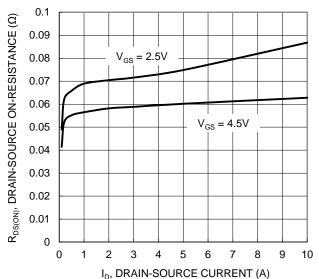


Figure 3. Typical On-Resistance vs Drain Current and Gate Voltage

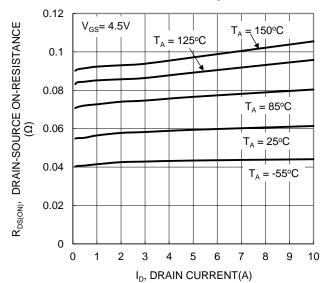
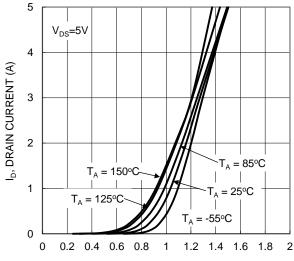


Figure 5. Typical On-Resistance vs Drain Current and Junction Temperature



 V_{GS} , GATE-SOURCE VOLTAGE (V) Figure 2. Typical Transfer Characteristic

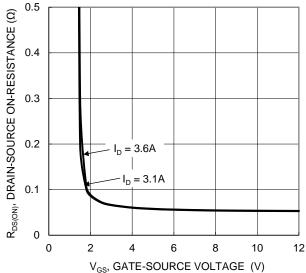


Figure 4. Typical Transfer Characteristic

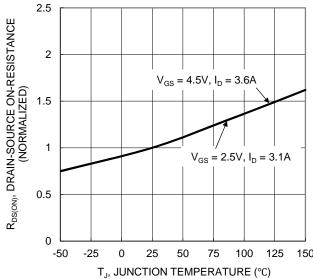


Figure 6. On-Resistance Variation with Junction Temperature



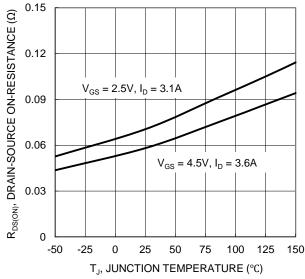
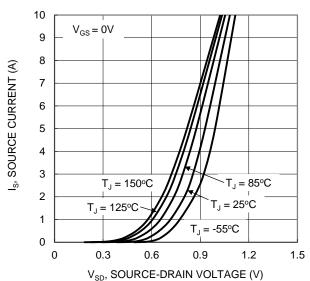


Figure 7. On-Resistance Variation with Junction Temperature



V_{SD}, SOURCE-DRAIN VOLTAGE (V) Figure 9. Diode Forward Voltage vs. Current

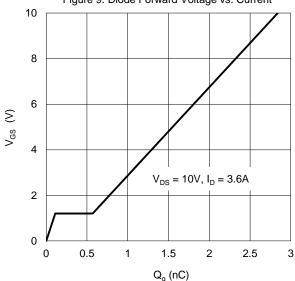


Figure 11. Gate Charge

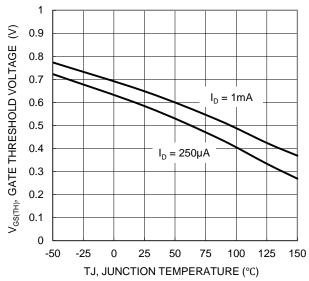


Figure 8. Gate Threshold Variation vs Junction Temperature

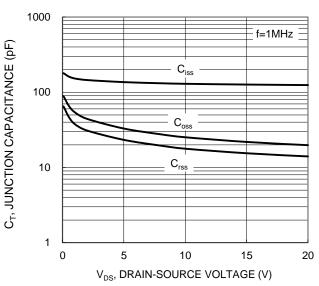
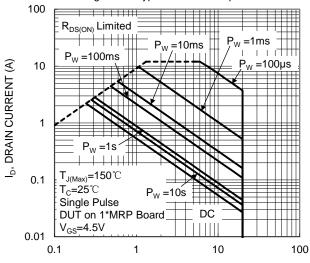


Figure 10. Typical Junction Capacitance



V_{DS}, DRAIN-SOURCE VOLTAGE (V) Figure 12. SOA, Safe Operation Area



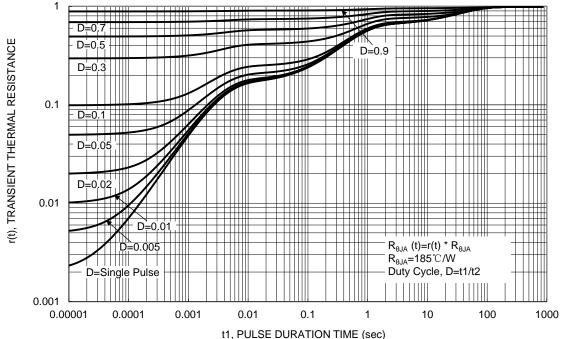


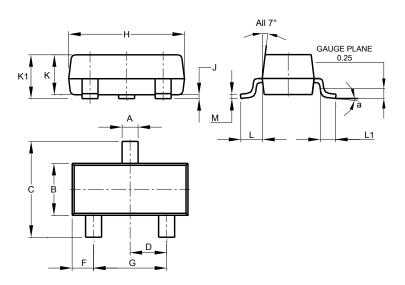
Figure 13. Transient Thermal Resistance



Package Outline Dimensions

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.

SOT23

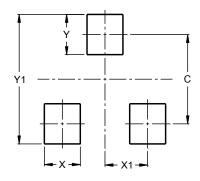


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
В	1.20	1.40	1.30				
С	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
J	0.013	0.10	0.05				
K	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
а	0°	8°	_				
All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/_files/datasheets/ap02001.pdf for the latest version.

SOT23



Dimensions	Value (in mm)				
С	2.0				
Х	0.8				
X1	1.35				
Y	0.9				
Y1	2.9				

January 2016



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